



Data sheet acquired from Harris Semiconductor SCHS198C

November 1997 - Revised May 2003

# High Speed CMOS Logic Dual 4-Stage Static Shift Register

#### Features

- Maximum Frequency, Typically 60MHz
   C<sub>L</sub> = 15pF, V<sub>CC</sub> = 5V, T<sub>A</sub> = 25°C
- · Positive-Edge Clocking
- Overriding Reset
- · Buffered Inputs and Outputs
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity:  $N_{IL}$  = 30%,  $N_{IH}$  = 30% of  $V_{CC}$  at  $V_{CC}$  = 5V

## Description

The 'HC4015 consists of two identical, independent, 4-stage serial-input/parallel-output registers. Each register has independent Clock (CP) and Reset (MR) inputs as well as a single serial Data input. "Q" outputs are available from each of the four stages on both registers. All register stages are D-type, master-slave flip-flops. The logic level present at the Data input is transferred into the first register stage and shifted over one stage at each positive- going clock transition. Resetting of all stages is accomplished by a high level on the reset line.

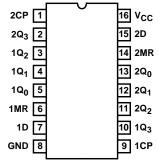
The device can drive up to 10 low power Schottky equivalent loads. The 'HC4015 is an enhanced version of equivalent CMOS types.

## **Ordering Information**

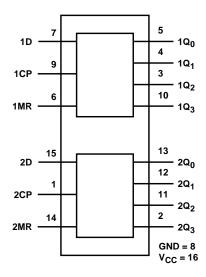
PART NUMBER	TEMP. RANGE (°C)	PACKAGE		
CD54HC4015F3A	-55 to 125	16 Ld CERDIP		
CD74HC4015E	-55 to 125	16 Ld PDIP		
CD74HC4015M	-55 to 125	16 Ld SOIC		

#### **Pinout**

CD54HC4015 (CERDIP) CD74HC4015 (PDIP, SOIC) TOP VIEW



# Functional Diagram



#### TRUTH TABLE

	INPUTS		OUTPUTS							
СР	D	R	Q <sub>0</sub>	Q <sub>1</sub>	Q <sub>2</sub>	$Q_3$				
1	I	L	L	q' <sub>0</sub>	q' <sub>1</sub>	q' <sub>2</sub>				
1	h	L	Н	q' <sub>0</sub>	q' <sub>1</sub>	q' <sub>2</sub>				
$\downarrow$	Х	L	q'o	q' <sub>1</sub>	q' <sub>2</sub>	q'3				
Х	Х	Н	L	L	L	L				

H = High Voltage Level

h = High Voltage Level One Set-up Time Prior to the Low to High Clock Transition

L = Low Voltage Level

I = Low Voltage Level One Set-up Time Prior to the Low to High Clock Transition

X = Don't Care.

↑ = Low to High Clock Transition

 $\downarrow$  = High to Low Clock Transition

 $q'_n$  = Lower case letters indicate the state of the referenced output one set-up time prior to the Low to High clock transition.

#### CD54HC4015, CD74HC4015

#### **Absolute Maximum Ratings** Thermal Information $\theta_{JA}$ (°C/W) DC Supply Voltage, V<sub>CC</sub> .....-0.5V to 7V Thermal Resistance (Typical, Note 1) DC Input Diode Current, I<sub>IK</sub> For $V_I < -0.5V$ or $V_I > V_{CC} + 0.5V$ ......±20mA M (SOIC) Package..... DC Output Diode Current, IOK For $V_O < -0.5V$ or $V_O > V_{CC} + 0.5V$ ......±20mA Maximum Storage Temperature Range .....-65°C to 150°C DC Output Source or Sink Current per Output Pin, IO Maximum Lead Temperature (Soldering 10s)......300°C (SOIC - Lead Tips Only) **Operating Conditions** Temperature Range, T<sub>A</sub> . . . . . . . . . . . . . . . . -55°C to 125°C Supply Voltage Range, V<sub>CC</sub> HC Types ......2V to 6V DC Input or Output Voltage, V<sub>I</sub>, V<sub>O</sub> . . . . . . . . . . . . . . 0V to V<sub>CC</sub> Input Rise and Fall Time 4.5V...... 500ns (Max)

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

#### NOTE

1. The package thermal impedance is calculated in accordance with JESD 51-7.

## **DC Electrical Specifications**

			TEST CONDITIONS			25°C			-40°C TO 85°C		-55°C TO 125°C	
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
High Level Input	V <sub>IH</sub>	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V <sub>IL</sub>	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V <sub>OH</sub>	V <sub>IH</sub> or V <sub>IL</sub>	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	1		-	-	-	-	-	-	-	-	-	٧
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	٧
1.12 20000			-5.2	6	5.48	-	-	5.34	-	5.2	-	٧
Low Level Output	V <sub>OL</sub>	V <sub>IH</sub> or V <sub>IL</sub>	0.02	2	-	-	0.1	-	0.1	-	0.1	٧
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	٧
000 2000				0.02	6	-	-	0.1	-	0.1	-	0.1
Low Level Output	1		-	-	-	-	-	-	-	-	-	٧
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	٧
1112 20000			5.2	6	-	-	0.26	-	0.33	-	0.4	٧
Input Leakage Current	Ι <sub>Ι</sub>	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μΑ
Quiescent Device Current	Icc	V <sub>CC</sub> or GND	0	6	-	ı	8	-	80	-	160	μΑ

# CD54HC4015, CD74HC4015

# **Prerequisite for Switching Specifications**

			25	°С	-40°C T	O 85°C	-55°C T		
PARAMETER	SYMBOL	V <sub>CC</sub> (V)	MIN	MAX	MIN	MAX	MIN	MAX	UNITS
Maximum Clock	f <sub>MAX</sub>	2	6	-	5	-	4	-	MHz
Frequency		4.5	30	-	24	-	20	-	MHz
		6	35	-	28	-	24	-	MHz
Clock Pulse Width	t <sub>W</sub>	2	80	-	100	-	120	-	ns
		4.5	16	-	20	-	24	-	ns
		6	14	-	17	-	20	-	ns
MR Pulse Width	t <sub>W</sub>	2	150	-	190	-	225	-	ns
		4.5	30	-	38	-	45	-	ns
		6	26	-	33	-	38	-	ns
MR Recovery Time	tREC	2	50	-	65	-	75	-	ns
		4.5	10	-	13	-	15	-	ns
		6	9	-	11	-	13	-	ns
Set-up Time, Data-In to CP	tsul, tsuh	2	60	-	75	-	90	-	ns
		4.5	12	-	15	-	18	-	ns
		6	10	-	13	-	15	-	ns
Hold Time,	tH	2	0	-	0	-	0	-	ns
Data-In to CP		4.5	0	-	0	-	0	-	ns
		6	0	-	0	-	0	-	ns

## **Switching Specifications** Input $t_r$ , $t_f = 6ns$

		TEST	Vcc	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Propagation Delay (Figure 1)	t <sub>PLH,</sub>	C <sub>L</sub> = 50pF	2	-	-	175	-	220	-	270	ns
Clock to Q <sub>n</sub>	t <sub>PHL</sub>		4.5	-	-	35	-	44	-	54	ns
		C <sub>L</sub> =15pF	5	-	14	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	30	-	37	-	46	ns
MR to Q <sub>n</sub> , (Clock High)	t <sub>PLH</sub> ,	C <sub>L</sub> = 50pF	2	-	-	275	-	345	-	415	ns
	t <sub>PHL</sub>		4.5	-	-	55	-	64	-	83	ns
		C <sub>L</sub> =15pF			25	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	47	-	54	-	71	ns
MR to Q <sub>n</sub> , (Clock Low)	t <sub>PLH,</sub> t <sub>PHL</sub>	C <sub>L</sub> = 50pF	2	-	-	325	-	400	-	490	ns
			4.5	-	-	65	-	81	-	98	ns
		C <sub>L</sub> =15pF			25	-	-	-	-	-	ns
		C <sub>L</sub> = 50pF	6	-	-	55	-	69	-	83	ns
Output Transition Time	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
(Figure 1)			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C <sub>IN</sub>	C <sub>L</sub> = 50pF	-	-	-	10	-	10	-	10	pF
Maximum Clock Frequency	f <sub>MAX</sub>	C <sub>L</sub> =15pF	5	-	60	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 2, 3)	C <sub>PD</sub>	C <sub>L</sub> =15pF	5	-	43	-	-	-	-	-	pF

- 2.  $C_{PD}$  is used to determine the dynamic power consumption, per shift register.

  3.  $P_D = V_{CC}^2 f_i + \sum C_L V_{CC}^2$  where  $f_i$  = Input Frequency,  $C_L$  = Output Load Capacitance,  $V_{CC}$  = Supply Voltage.

# Test Circuit and Waveform

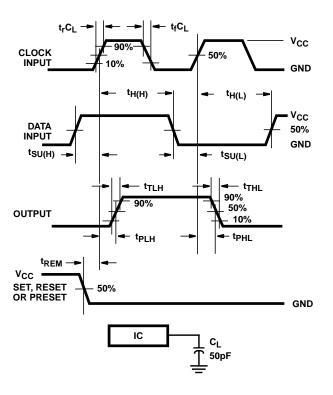


FIGURE 1. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

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#### PACKAGING INFORMATION

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
5962-8995301EA	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8995301EA CD54HC4015F3A
CD54HC4015F3A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8995301EA CD54HC4015F3A
CD54HC4015F3A.A	Active	Production	CDIP (J)   16	25   TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	5962-8995301EA CD54HC4015F3A
CD74HC4015E	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4015E
CD74HC4015E.A	Active	Production	PDIP (N)   16	25   TUBE	Yes	NIPDAU	N/A for Pkg Type	-55 to 125	CD74HC4015E
CD74HC4015M	Active	Production	SOIC (D)   16	40   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4015M
CD74HC4015M.A	Active	Production	SOIC (D)   16	40   TUBE	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4015M

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

## PACKAGE OPTION ADDENDUM

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and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF CD54HC4015, CD74HC4015:

Catalog : CD74HC4015

• Military : CD54HC4015

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

# **PACKAGE MATERIALS INFORMATION**

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#### **TUBE**



\*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC4015E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4015E	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4015E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4015E.A	N	PDIP	16	25	506	13.97	11230	4.32
CD74HC4015M	D	SOIC	16	40	507	8	3940	4.32
CD74HC4015M.A	D	SOIC	16	40	507	8	3940	4.32

# D (R-PDS0-G16)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



# 14 LEADS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



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